## 11MHZ CMOS Rail-to-Rail IO Opamps

#### **Features**

• Single-Supply Operation from +2.1V ~ +5.5V

• Rail-to-Rail Input / Output

• Gain-Bandwidth Product: 11MHz (Typ.)

Low Input Bias Current: 1pA (Typ.)

Low Offset Voltage: 3.5mV (Max.)

• High Slew Rate: 9V/µs

Settling Time to 0.1% with 2V Step: 0.3μs

Low Noise: 8nV/ Hz @10kHz

Quiescent Current: 1.1mA per Amplifier (Typ.)

• Operating Temperature: -40°C ~ +125°C

• Small Package:

LMV721 Available in SOT23-5 , SC70-5 , SOP-8 and MSOP-8 Packages

LMV722 Available in SOP-8 and MSOP-8 Packages

LMV724 Available in SOP-14 and TSSOP-14 Packages

LMV721N Available in SOT23-6 and SC70-6 Packages

## **General Description**

The LMV72X have a high gain-bandwidth product of 11 MHz, a slew rate of 9V/ µs, and a quiescent current of 1.1mA per amplifier at 5V. The LMV721N has a power-down disable feature that reduces the supply current to 90nA. The LMV72X are designed to provide optimal performance in low voltage and low noise systems. They provide rail-to-rail output swing into heavy loads. The input common mode voltage range includes ground, and the maximum input offset voltage is 3.5mV for LMV72X. They are specified over the extended industrial temperature range (-40°C to +125°C). The operating range is from 2.1V to 5.5V. The LMV721 single is available in Green SC70-5, SOT23-5, SOP-8 and MSOP-8 packages. The LMV722 dual is available in Green SOP-14 and TSSOP-14 packages. The LMV721N single with shutdown is available in Green SOT23-6 and SC70-6 packages.

### **Applications**

- Sensors
- Active Filters
- Cellular and Cordless Phones
- Laptops and PDAs

- Audio
- Handheld Test Equipment
- Battery-Powered Instrumentation
- A/D Converters

#### **Ordering Information**

DEVICE	Package Type	MARKING	Packing	Packing Qty
LMV721M5/TR	SOT23-5L	V721	REEL	3000pcs/reel
LMV721M7/TR	SC70-5L	V721	REEL	3000pcs/reel
LMV721M/TR	SOP-8L	LMV721	REEL	2500pcs/reel
LMV721MM/TR	MSOP-8	V721	REEL	3000pcs/reel
LMV721NM6/TR	SOT23-6L	V721N	REEL	3000pcs/reel
LMV721NM7/TR	SC70-6L	V721N	REEL	3000pcs/reel
LMV722M/TR	SOP-8L	LMV722	REEL	2500pcs/reel
LMV722MM/TR	MSOP-8L	LMV722	REEL	3000pcs/reel
LMV724M/TR	SOP-14L	LMV724	REEL	2500pcs/reel
LMV724MT/TR	TSSOP-14L	LMV724	REEL	2500pcs/reel

## **Pin Configuration**

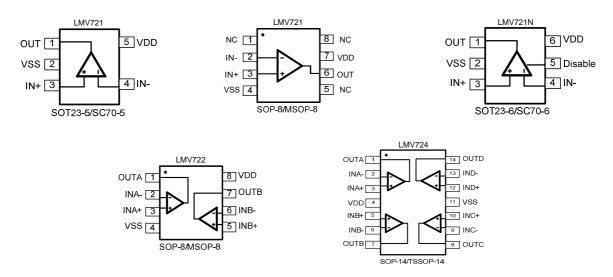


Figure 1. Pin Assignment Diagram

## **Absolute Maximum Ratings**

Condition	Min	Max				
Power Supply Voltage (V <sub>DD</sub> to Vss)	-0.5V	+7.5V				
Analog Input Voltage (IN+ or IN-)	Vss-0.5V	V <sub>DD</sub> +0.5V				
PDB Input Voltage	Vss-0.5V	+7V				
Operating Temperature Range	-40°C	+125°C				
Junction Temperature	+160	)°C				
Storage Temperature Range	-55°C	+150°C				
Lead Temperature (soldering, 10sec)	+260	o°C				
Package Thermal Resistance (TA=+25℃)						
SOP-8, θ <sub>JA</sub>	125°0	C/W				
MSOP-8, θ <sub>JA</sub>	216°0	C/W				
SOT23-5, θ <sub>JA</sub>	190°0	C/W				
SOT23-6, θ <sub>JA</sub>	190°0	C/W				
SC70-5, θ <sub>JA</sub>	333°0	333°C/W				
ESD Susceptibility	•					
НВМ	8K	8KV				
MM	400	400V				

**Note:** Stress greater than those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions outside those indicated in the operational sections of this specification are not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

## **Electrical Characteristics**

(At Vs=5V,  $T_A$  = +25  $^{\circ}\text{C}$  ,  $V_{\text{CM}}$  = V<sub>S</sub>/2,  $R_L$  = 600  $^{\Omega}$  , unless otherwise noted.)

		LMV721/2/4/1N						
0.00.00	COMPITIONS	TYP	MIN/MAX OVER TEMPERATURE					
PARAMETER	CONDITIONS	+25℃	+25℃	0℃ to	-40℃ to 85℃	-40 ℃ to	UNITS	MIN /
INPUT CHARACTERISTICS			700	10 65 C	125 C		IWAX	
Input Offset Voltage (Vos)		0.8	3.5	3.9	4.3	4.6	mV	MAX
Input Bias Current (I <sub>B</sub> )		1	0.0	0.0	1.0	1.0	pА	TYP
Input Offset Current (Ios)		1					pА	TYP
Input Common Mode Voltage Range (V <sub>CM</sub> )	V <sub>S</sub> = 5.5V	-0.1 to					V	TYP
par eemage (ge (ge)		+5.6						
Common Mode Rejection Ratio (CMRR)	$V_S = 5.5V$ , $V_{CM} = -0.1V$ to 4V	82	65	64	64	63	dB	MIN
	$V_S = 5.5V$ , $V_{CM} = -0.1V$ to 5.6V	75					dB	MIN
Open-Loop Voltage Gain (A <sub>OL</sub> )	$R_L = 600\Omega, V_O = 0.15V \text{ to } 4.85V$	90	80	76	75	68	dB	MIN
	$R_L = 10k\Omega, V_O = 0.05V \text{ to } 4.95V$	108					dB	MIN
Input Offset Voltage Drift ( $\Delta V_{OS}/\Delta_T$ )		2.4					μV/°C	TYP
OUTPUT CHARACTERISTICS		<u> </u>						
Output Voltage Swing from Rail	R <sub>L</sub> = 600Ω	0.1					V	TYP
	$R_L = 10k\Omega$	0.015					V	TYP
Output Current (I <sub>OUT</sub> )		70	55	45	42	38	mA	MIN
Closed-Loop Output Impedance	f = 100kHz, G = 1	7.5					Ω	TYP
POWER-DOWN DISABLE				•			•	
Turn-On Time		1.1					μs	TYP
Turn-Off Time		0.3					μs	TYP
DISABLE Voltage-Off			0.8				V	MAX
DISABLE Voltage-On			2				V	MIN
POWER SUPPLY								
Operating Voltage Range			2.1	2.1	2.1	2.1	V	MIN
			5.5	5.5	5.5	5.5	٧	MAX
Power Supply Rejection Ratio (PSRR)	V <sub>S</sub> = +2.5V to +5.5V							
	$V_{CM} = (-V_S) + 0.5V$	91	74	72	72	68	dB	MIN
Quiescent Current/Amplifier (IQ)	I <sub>OUT</sub> = 0	1.1	1.5	1.65	1.7	1.85	mA	MAX
Supply Current when Disabled		90					nA	MAX
(LMV721N Only)								

## **Electrical Characteristics**

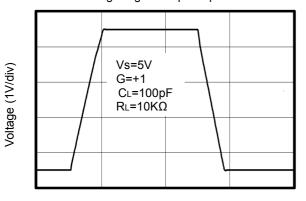
(At Vs=5V, T<sub>A</sub> = +25  $^{\circ}\text{C}$  , V<sub>CM</sub> = V<sub>S</sub>/2, R<sub>L</sub> = 600  $^{\Omega}$  , unless otherwise noted.)

		LMV721/2/4/1N							
DADAMETED	CONDITIONS	TYP	TYP MIN/MAX OVER TEMPERATURE						
PARAMETER	CONDITIONS	+25℃	. 05.00	0℃ to	-40℃ to   -40℃ to		UNITS	MIN /	
		<b>+25</b> C	+25℃	70℃	85℃	125℃	UNITS	MAX	
DYNAMIC PERFORMANCE					•				
Gain-Bandwidth Product (GBP)	$R_L = 10k\Omega, C_L = 100pF$	11					MHz	TYP	
Phase Margin (φ <sub>O</sub> )	$R_L = 10k\Omega, C_L = 100pF$	51					Degrees	TYP	
Full Power Bandwidth (BWP)	$<$ 1% distortion, R <sub>L</sub> = $600\Omega$	400					kHz	TYP	
Slew Rate (SR)	G = +1, 2V Step, $R_L$ = 10k $\Omega$	9					V/µs	TYP	
Settling Time to 0.1% (t <sub>S</sub> )	G = +1, 2V Step, R <sub>L</sub> = 600Ω	0.3					μs	TYP	
Overload Recovery Time	$V_{IN}$ ·Gain = VS, $R_L$ = 600 $\Omega$	1.5					μs	TYP	
NOISE PERFORMANCE									
Voltage Noise Density (e <sub>n</sub> )	f = 1kHz	11.5					$nV/\sqrt{Hz}$	TYP	
	f = 10kHz	8					$nV/\sqrt{Hz}$	TYP	

## **Typical Performance characteristics**

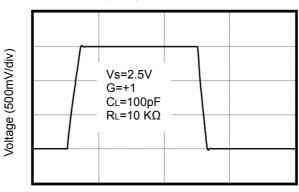
(At Vs=5V, TA = +25  $^{\circ}$ C, V<sub>CM</sub> = Vs/2, R<sub>L</sub> = 600 $\Omega$ , unless otherwise noted.)

#### Large-Signal Step Response



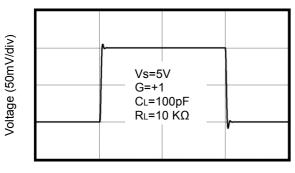
## Time (1µs/div)

Large-Signal Step Response



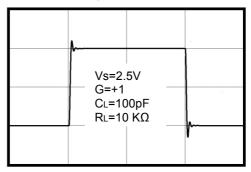
Time (1µs/div)

Small-Signal Step Response



Time (1µs/div)

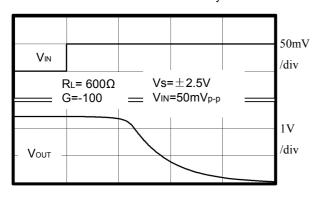
Small-Signal Step Response



Voltage (50mV/div)

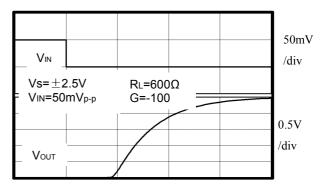
Time (1µs/div)

Positive Overload Recovery



Time (2µs/div)

Negative Overload Recovery



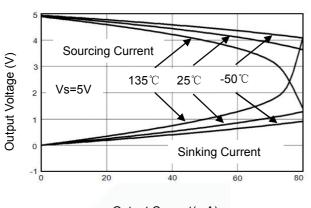
Time (2µs/div)

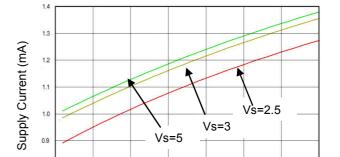
125

## **Typical Performance characteristics**

Output Voltage Swing vs.Output Current

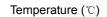
(At Vs=5V, TA = +25  $^{\circ}$ C, V<sub>CM</sub> = Vs/2, R<sub>L</sub> = 600 $\Omega$ , unless otherwise noted.)





Supply Current vs. Temperature

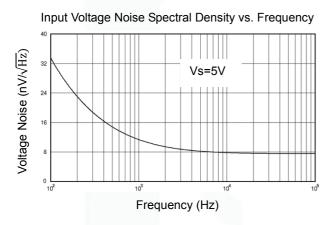
Output Current(mA)

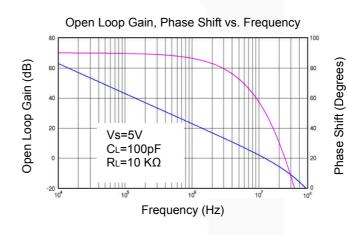


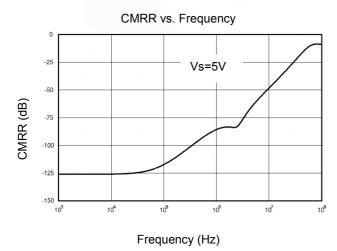
25

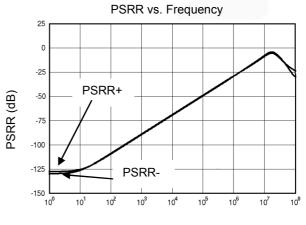
0.8

-25









Frequency (Hz)

## **Application Note**

#### Size

LMV72X series op amps are unity-gain stable and suitable for a wide range of general-purpose applications. The small footprints of the LMV72X series packages save space on printed circuit boards and enable the design of smaller electronic products.

#### **Power Supply Bypassing and Board Layout**

LMV72X series operates from a single 2.1V to 5.5V supply or dual  $\pm 1.05$ V to  $\pm 2.75$ V supplies. For best performance, a  $0.1\mu$ F ceramic capacitor should be placed close to the  $V_{DD}$  pin in single supply operation. For dual supply operation, both  $V_{DD}$  and  $V_{SS}$  supplies should be bypassed to ground with separate  $0.1\mu$ F ceramic capacitors.

#### **Low Supply Current**

The low supply current (typical 1.1mA per channel) of LMV72X series will help to maximize battery life. They are ideal for battery powered systems

#### **Operating Voltage**

LMV72X series operate under wide input supply voltage (2.1V to 5.5V). In addition, all temperature specifications apply from -40 °C to +125 °C. Most behavior remains unchanged throughout the full operating voltage range. These guarantees ensure operation throughout the single Li-lon battery lifetime

#### Rail-to-Rail Input

The input common-mode range of LMV72X series extends 100mV beyond the supply rails (V  $_{SS}$ -0.1V to V $_{DD}$ +0.1V). This is achieved by using complementary input stage. For normal operation, inputs should be limited to this range.

#### **Rail-to-Rail Output**

Rail-to-Rail output swing provides maximum possible dynamic range at the output. This is particularly important when operating in low supply voltages. The output voltage of LMV72X series can typically swing to less than 2mV from supply rail in light resistive loads (>100k $\Omega$ ), and 15mV of supply rail in moderate resistive loads (10k $\Omega$ ).

#### **Capacitive Load Tolerance**

The LMV72X family is optimized for bandwidth and speed, not for driving capacitive loads. Output capacitance will create a pole in the amplifier's feedback path, leading to excessive peaking and potential oscillation. If dealing with load capacitance is a requirement of the application, the two strategies to consider are (1) using a small resistor in series with the amplifier's output and the load capacitance and (2) reducing the bandwidth of the amplifier's feedback loop by increasing the overall noise gain. Figure 2. shows a unity gain follower using the series resistor strategy. The resistor isolates the output from the capacitance and, more importantly, creates a zero in the feedback path that compensates for the pole created by the output capacitance.

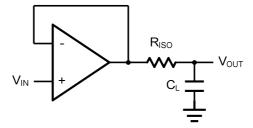


Figure 2. Indirectly Driving a Capacitive Load Using Isolation Resistor

The bigger the  $R_{ISO}$  resistor value, the more stable  $V_{OUT}$  will be. However, if there is a resistive load  $R_L$  in parallel with the capacitive load, a voltage divider (proportional to  $R_{ISO}/R_L$ ) is formed, this will result in a gain error.

The circuit in Figure 3 is an improvement to the one in Figure 2. R<sub>F</sub> provides the DC accuracy by feed-forward the V<sub>IN</sub> to R<sub>L</sub>. C<sub>F</sub>

and  $R_{\rm ISO}$  serve to counteract the loss of phase margin by feeding the high frequency component of the output signal back to the amplifier's inverting input, thereby preserving the phase margin in the overall feedback loop. Capacitive drive can be increased by increasing the value of  $C_F$ . This in turn will slow down the pulse response.

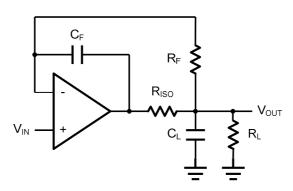


Figure 3. Indirectly Driving a Capacitive Load with DC Accuracy

## **Typical Application Circuits**

### **Differential amplifier**

The differential amplifier allows the subtraction of two input voltages or cancellation of a signal common the two inputs. It is useful as a computational amplifier in making a differential to single-end conversion or in rejecting a common mode signal. Figure 4. shown the differential amplifier using LMV72X.

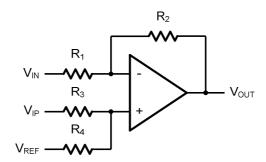


Figure 4. Differential Amplifier

$$V_{\text{OUT}} = \left(\frac{R_1 + R_2}{R_3 + R_4}\right) \frac{R_4}{R_1} V_{\text{IN}} - \frac{R_2}{R_1} V_{\text{IP}} + \left(\frac{R_1 + R_2}{R_3 + R_4}\right) \frac{R_3}{R_1} V_{\text{REF}}$$

If the resistor ratios are equal (i.e. R<sub>1</sub>=R<sub>3</sub> and R<sub>2</sub>=R<sub>4</sub>), then

$$V_{\text{OUT}} = \frac{R_2}{R_1} (V_{\text{IP}} - V_{\text{IN}}) + V_{\text{REF}}$$

#### **Low Pass Active Filter**

The low pass active filter is shown in Figure 5. The DC gain is defined by  $-R_2/R_1$ . The filter has a -20dB/decade roll-off after its corner frequency  $f_C=1/(2\pi R_3C_1)$ .

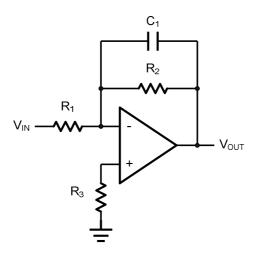


Figure 5. Low Pass Active Filter

### **Instrumentation Amplifier**

The triple LMV72X can be used to build a three-op-amp instrumentation amplifier as shown in Figure 6. The amplifier in Figure 6 is a high input impedance differential amplifier with gain of  $R_2/R_1$ . The two differential voltage followers assure the high input impedance of the amplifier.

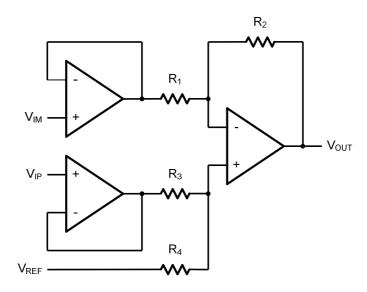
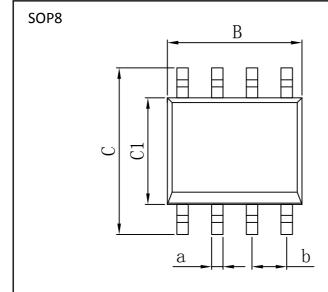
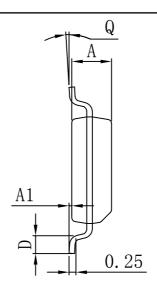


Figure 6. Instrument Amplifier

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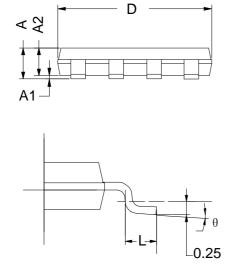


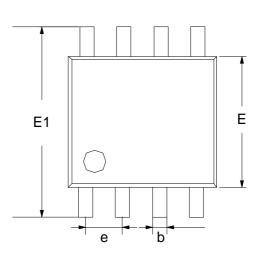




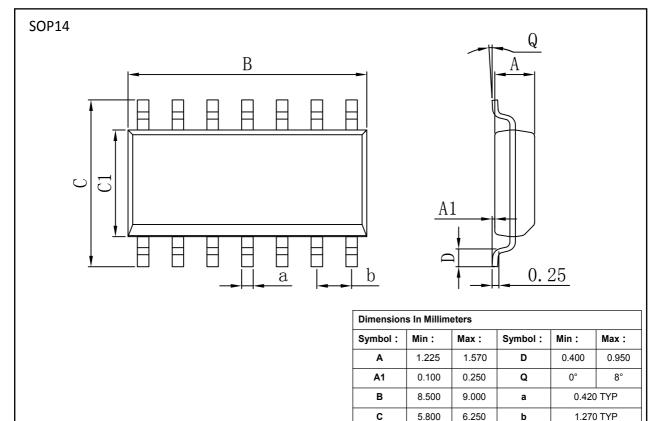
Dimensions In Millimeters							
Symbol:	Min:	Max:	Symbol :	Min:	Max:		
Α	1.225	1.570	D	0.400	0.950		
A1	0.100	0.250	Q	0°	8°		
В	4.800	5.100	а	0.420	TYP		
С	5.800	6.250	b	1.270	) TYP		
C1	3.800	4.000		•			

MSOP8





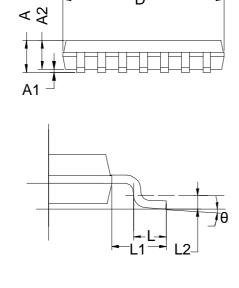
Dimensions In Millimeters							
Symbol :	Min:	Max:	Symbol :	Min :	Max:		
Α	0.800	1.200	E1	4.700	5.100		
A1	0	0.200	L	0.410	0.650		
A2	0.760	0.970	θ	0°	6°		
D	2.900	3.100	b	0.300 TYP			
E	2.900	3.100	е	0.650 TYP			

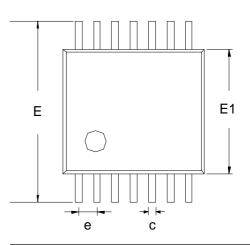


C1

3.800

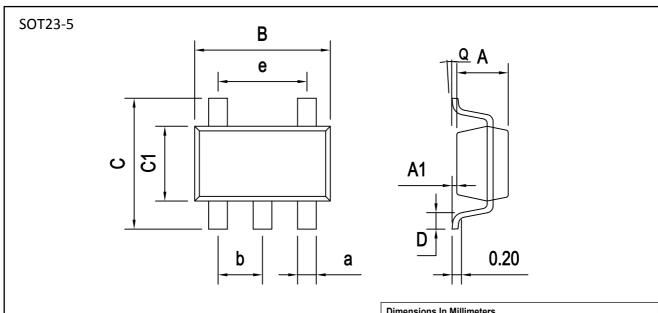




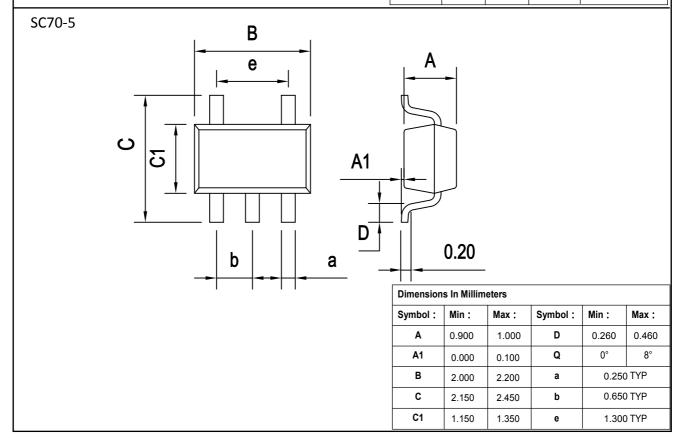


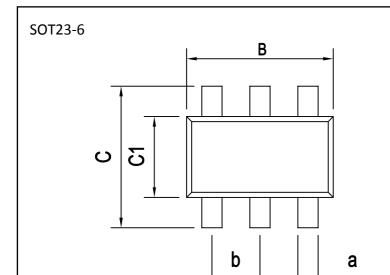
4.000

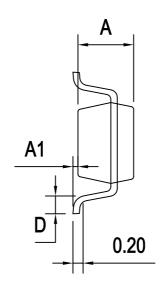
Dimensions In Millimeters						
Symbol:	Min :	Max:	Symbol :	Min:	Max:	
Α	0.950	1.200	E1	4.300	4.500	
A1	0.050	0.150	L	0.450	0.750	
A2	0.800	1.000	θ	0°	8°	
В	0.200	0.280	е	0.650	BSC	
С	0.100	0.190	L1	1.000	REF	
D	4.860	5.060	L2	1.250	BSC	
Е	6.200	6.600				



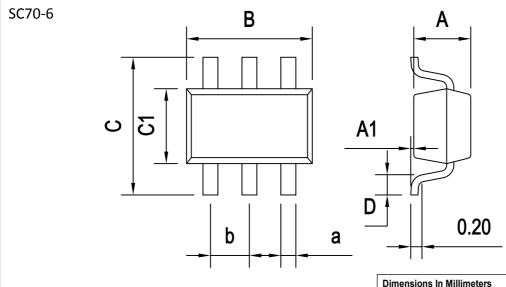
Dimensions In Millimeters							
Symbol:	Min:	Max:	Symbol:	Min:	Max:		
Α	1.050	1.150	D	0.300	0.600		
A1	0.000	0.100	Q	0°	8°		
В	2.820	3.020	а	0.400 TYP			
С	2.650	2.950	b	0.950 TYP			
C1	1.500	1.700	е	1.900 TYP			







Dimensions In Millimeters							
Symbol:	Min:	Max:	Symbol:	Min:	Max:		
Α	1.050	1.150	D	0.300	0.600		
A1	0.000	0.100	Q	0°	8°		
В	2.820	3.020	а	0.400 TYP			
С	2.650	2.950	b	0.950	TYP		
C1	1.500	1.700					



Dimensions In Millimeters							
Symbol:	Min:	Max:	Symbol:	Min:	Max:		
Α	0.900	1.000	D	0.260	0.460		
A1	0.000	0.100	Q	0°	8°		
В	2.000	2.200	а	0.250 TYP			
С	2.150	2.450	b	0.650	) TYP		
C1	1.150	1.350					

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